

AH1822

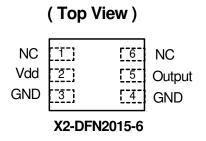
### MICROPOWER OMNIPOLAR HALL-EFFECT SENSOR SWITCH

### Description

AH1822 is comprised of two Hall effect plates and an open-drain output driver, mainly designed for battery-operation, hand-held equipment (such as Cellular and Cordless Phone, PDA). The total power consumption in normal operation is typically  $24\mu W$  with a 3V power source.

Either north or south pole of sufficient strength will turn the output on. The output will be turned off under no magnetic field. While the magnetic flux density (**B**) is larger than operating point (**Bop**), the output will be turned on (low), the output is held until **B** is lower than release point (**Brp**), then turned off.

# Pin Assignments



**Features** 

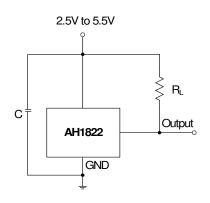
- Micropower Operation
- Operation with Magnetic Field of Either North or South Pole (Omnipolar)
- 2.5V to 5.5V Battery Operation
- Chopper Stabilized
  - Superior Temperature Stability
  - Extremely Low Switch-Point Drift
  - Insensitive to Physical Stress
- Good RF Noise Immunity
- -40°C to +85°C Operating Temperature
- ESD (HBM) > 5kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Note: 4. NC is "No Connection" which is recommended to be tied to ground.

### Applications

- Cover Switch in Clam-Shell Cellular Phones
- Cover Switch in Notebook PC/PDA
- Contact-Less Switch in Consumer Products
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## **Typical Applications Circuit**



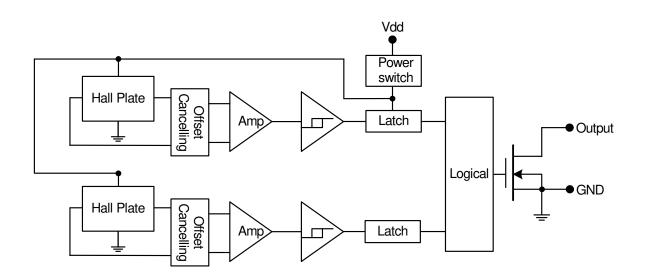
Note: 5. C is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R<sub>L</sub> is the pull-up resistor, the recommended resistance is 10kΩ to 100kΩ.



## **Pin Descriptions**

Pin Name	P/I/O	Description
Vdd	P/I	Power Supply Input
GND	P/I	Ground
Output	0	Output Pin
NC	NC	No Connected

## Functional Block Diagram



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
V <sub>dd</sub>	Supply Voltage	7	V	
В	Magnetic Flux Density	Unlimited		
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
PD	Package Power Dissipation	230	mW	
TJ	Maximum Junction Temperature	+150	°C	

## **Recommended Operating Conditions**

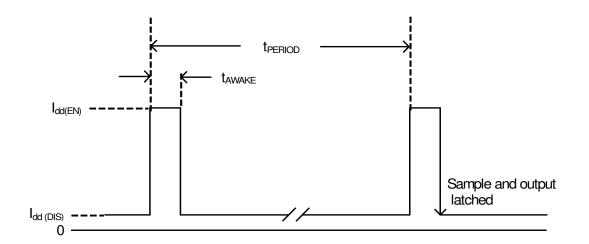
Symbol	Parameter	Conditions	Rating	Unit
V <sub>dd</sub>	Supply Voltage	Operating	2.5 to 5.5	V
T <sub>A</sub>	Operating Temperature Range	Operating	-40 to +85	°C



## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, $V_{dd}$ = 3V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OUT</sub>	Output On Voltage	I <sub>OUT</sub> =1mA	_	0.1	0.3	V
IOFF	Output Leakage Current	V <sub>OUT</sub> =5.5V, Output off		<0.1	1	μA
I <sub>dd(EN)</sub>		Chip enable, $T_A = +25^{\circ}C$ , $V_{dd} = 3V$		3	6	mA
I <sub>dd(EN)</sub>		Chip enable, $T_{A}$ =-40 to +85°C, V <sub>dd</sub> = 2.5V to 5.5V	_	3	10	mA
I <sub>dd(DIS)</sub>		Chip disable, $T_{A}$ = +25°C, $V_{dd}$ = 3V		5	10	μA
I <sub>dd(DIS)</sub>	Supply Current	Chip disable, $T_{A}$ = -40 to +85°C, V <sub>dd</sub> = 2.5V to 5.5V	_	5	18	μΑ
I <sub>dd(AVG)</sub>		Average supply current, $T_{A}$ = +25°C, $V_{dd}$ = 3V	_	8	16	μA
I <sub>dd(AVG)</sub>		Average supply current, T <sub>A</sub> = -40 to +85°C, V <sub>dd</sub> = 2.5V to 5.5V	_	8	28	μA
f <sub>C</sub>	Chopping Frequency	For design information only		300		kHz
<b>t</b> AWAKE	Awake Time	(Note 6)		75	150	μs
<b>t</b> PERIOD	Period	(Note 6)		75	150	ms
D.C.	Duty Cycle		_	0.1		%

Notes: 6. When power is initially on, the operating V<sub>dd</sub> (2.5V to 5.5V) must be applied to be guaranteed for the output sampling. The output state is valid after the second operating phase (typical 150ms).



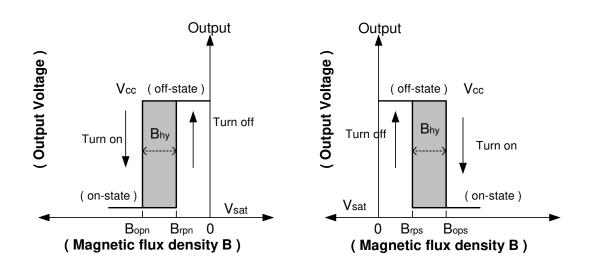


## Magnetic Characteristics (@T<sub>A</sub> = +25°C, V<sub>dd</sub> = 3V, unless otherwise specified. Notes 7 and 8)

					(1mT=10 Gauss
Symbol	Characteristic	Min	Тур	Max	Unit
Bops(South Pole to Brand Side)	On averta Daint	_	28	55	
Bopn(North Pole to Brand Side)	Operate Point	-55	-28	_	
Brps(South Pole to Brand Side)	Deleges Deint	10	20	_	Gauss
Brpn(North Pole to Brand Side)	Release Point	_	-20	-10	
Bhy(Bopx-Brpx)	Hysteresis	5	8	—	7

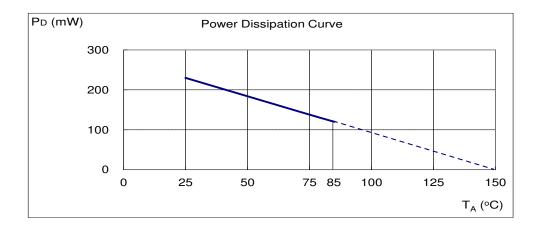
Notes:

7. Typical data is at T<sub>A</sub>= +25°C, V<sub>dd</sub> = 3V, and for design information only. 8. Operating point and release point will vary with supply voltage and operating temperature.



## **Performance Characteristics**

Γ	T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	110	120	130	140	150
	P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	74	55	37	18	0





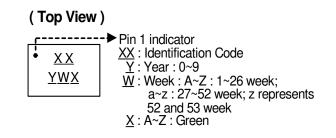
## AH 1822 - XXX - 7 Package Packing FT4: X2-DFN2015-6

7: Tape & Reel

Device	Package Code	Packaging	7" Tape	and Reel				
Device	Fackage Code	Fackaging	Quantity	Part Number Suffix				
AH1822-FT4-7	FT4	X2-DFN2015-6	3000/Tape & Reel	-7				
Note: 9. For packaging det	lote: 9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.							

## **Marking Information**

### (1) X2-DFN2015-6



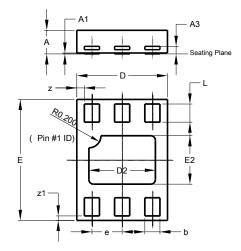
Part Number	Package	Identification Code
AH1822	X2-DFN2015-6	К7



## Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: X2-DFN2015-6

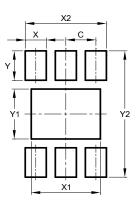


2	X2-DFN2015-6					
Dim	Min	Max	Тур			
Α	0.375	0.40	0.390			
A1	0	0.05	0.02			
A3	-	-	0.13			
b	0.20	0.30	0.25			
D	1.45	1.575	1.50			
D2	1.00	1.20	1.10			
е	-	-	0.50			
E	1.95	2.075	2.00			
E2	0.70	0.90	0.80			
L	0.25	0.35	0.30			
Z	-	-	0.125			
Z1	-	-	0.075			
All D	imens	ions ir	n mm			

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package type: X2-DFN2015-6

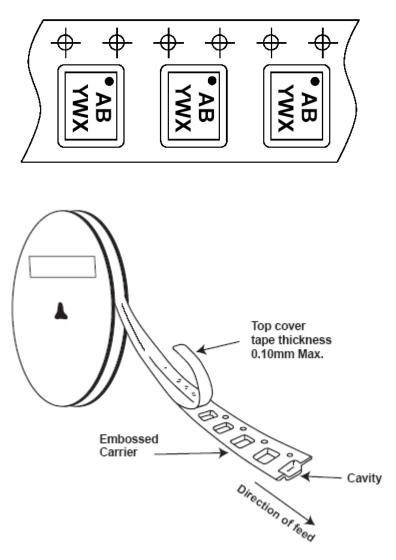


X2-DFN2015-6				
Dimensions	Value (in mm)			
C	0.500			
Х	0.350			
X1	1.150			
X2	1.350			
Y	0.500			
Y1	0.850			
Y2	2.150			



## **Taping Orientation**

### (1) X2-DFN2015-6



Notes: 10. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf.



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